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Contents

∨ii ix	Authors Conference Committee
	KEYNOTE SESSION AND LATEST TOPIC
11327 05	Pixelated mask optimization on quantum computers [11327-3]
	MACHINE LEARNING AND COMPUTATIONAL LITHOGRAPHY I
11327 06	Establishing fast, practical, full-chip ILT flows using machine learning (Invited Paper) [11327-4]
11327 07	Mask synthesis using machine learning software and hardware platforms (Invited Paper) [11327-5]
11327 09	Model based CAOPC flow for memory chips to improve performance and consistency of RET solutions [11327-41]
11327 0A	Physics based feature vector design: a critical step towards machine learning based inverse lithography [11327-7]
	MACHINE LEARNING AND COMPUTATIONAL LITHOGRAPHY II
11327 OB	Accurate etch modeling with massive metrology and deep-learning technology [11327-8]
11327 0C	SRAF printing prediction using artificial neural network [11327-9]
11327 0D	Improving ORC methods and hotspot detection with the usage of aerial images metrology [11327-10]
11327 OF	Fast all-angle Mask 3D for ILT patterning [11327-12]
	PROCESS CONTROL, RESIST MODELING
	FROCESS CONTROL, RESIST MODELING
11327 0G	Resist shrinkage during development: rigorous simulations and first compact model for OPC [11327-13]
11327 OH	Compact resist model using single convolution kernel [11327-14]

11327 01	Rigorous simulation of implant resist on topographic wafer [11327-15]
11327 OJ	Rigorous vase data fitting for ultrathin films [11327-16]
11327 OK	TrueMask ILT MWCO: full-chip curvilinear ILT in a day and full mask multi-beam and VSB writing in 12 hrs for 193i [11327-17]
	LITHOGRAPHY EQUIPMENT, FOCUS CONTROL
11327 OM	Divided spectrum illumination for high resolution flat panel display exposure tools [11327-19]
11327 ON	Investigating the fine line lithography process on the large-size organic panels for advanced packaging and development [11327-20]
11327 00	Accuracy improvement in advance lithography focus control [11327-21]
	DUV AND EUV MATCHING
11327 OS	Holistic alignment approach for on-product overlay improvement on DUV lithography process with combined solutions $[11327-24]$
11327 OT	A novel projection lens manipulator for high frequent overlay tuning [11327-25]
	OVERLAY AND CD CONTROL
11327 0U	Advanced high order field-to-field modeling for wafer edge control [11327-26]
11327 OV	Application of intra-field alignment to reduce wafer-to-wafer variation [11327-27]
11327 OW	Novel overlay correction using inline alignment station (iAS) for scanner [11327-28]
11327 0X	Improvement of SADP CD control in 7nm BEOL application [11327-48]
11327 OY	Through-the-mask (TTM) optical alignment for high volume manufacturing nanoimprint lithography systems [11327-30]
	POSTER SESSION
11327 OZ	Design and fabrication of UVLED array aligner for proximity and soft contact exposure [11327-31]

11327 11	Proteus SMO for process window improvement [11327-33]
11327 13	Approach for lightsource utilization improvement by extending Preventive Maintenance (PM) cycle along with performance monitoring feature [11327-35]
11327 16	Comparison of different lithographic source optimization methods based on compressive sensing [11327-38]
11327 17	Imaging performance enhancement by improvements of spectral performance stability and controllability on the cutting-edge [11327-39]
11327 19	Fast algorithm of the scanning lithographic metrics based on a quadratic imaging model and an integral transfer function $[11327-42]$
11327 1A	Target recovery process optimization to improve image based overlay performance for critical recording head manufacturing processes [11327-43]
11327 1B	KrF excimer laser-based patterning system for dual applications in both lithography and ablation [11327-45]
11327 1C	Evaluating and correcting pattern variability induced by OPC within regular array layout [11327-46]

Authors

Numbers in the index correspond to the last two digits of the seven-digit citation identifier (CID) article numbering system used in Proceedings of SPIE. The first five digits reflect the volume number. Base 36 numbering is employed for the last two digits and indicates the order of articles within the volume. Numbers start with 00, 01, 02, 03, 04, 05, 06, 07, 08, 09, 0A, 0B...0Z, followed by 10-1Z, 20-2Z, etc.

Ando, Miwako, 0M Arce, Gonzalo R., 16 Bald, Holger, OU, OV Bellmann, Enrico, OV Böcker, Paul, OS Bouaricha, Ali, OK Bouman, Wim, OT Bowser, Aaron, 1A Braam, Kyle, 06 Buhl, Stefan, OU Bushida, Satoru, 17 Buttgereit, Ute, 0D Cecil, Thomas, 06 Chang, Jonathan, 0X Chen, Kun-Yuan, 11 Chen, Rui, 16 Chen, Shoumian, 0A Chen, Xiuguo, 19 Chong, Nui, 0X Collins, Darin, 0J Dam, Thuc, 11 de Boeij, Wim, OT Depre, L., 1C Dineen, Cassidy, 00 Ding, Hua, 11 Dong, Lisong, 16 Emer, Wolfgang, OT Eto, Shigeru, OW Fahrni, Francis, OT Fan, Yongfa, OB Fan, Zhiqiang, OJ Feng, Mu, OB Feng, Yaobin, 09 Fujimura, Aki, OF, OK Gao, Ying, 0B Gardin, C., 1C Granik, Yuri, 0G Ha, Hyunjun, 0V Habets, Boris, OU, OV Hakko, Manabu, 0M Han, Sang-Jun, OS Hany Mousa, Sherif, 09 Hao, Xueli, 0O Hayashi, Nozomu, OY Hirai, Shinichirou, OY Hisamura, Toshiyuki, OX

Hoeer, Tobias, OU, OV

Hoppe, Wolfgang, 01 Hsu, Chris, 00 Hsu, Poya, 00 Hu, Hongmei, OB Hu, Sophia, 13 Huang, Jiun-Woei, 0Z Igarashi, Miwa, 17 lino, Satoshi, OY Itani, Toshiro, 1B Iwai, Toshiki, OY Izumi, Nozomu, 0M Jayaram, Srividya, 09 Ji, Liang, OB Jia, Jianjun, 11 Jiang, Hao, 19 Katou, Masahide, 17 Kawashima, Tohru, OY Khaira, Daman, 0G Kikuchi, Takahisa, 0W Kim, Cheolkyun, 0C Kim, Gwang-Gon, 0S Kim, Jangsun, OV Kim, Jung-Hwan, OS Kim, Jun-Yeob, OS Kim, Kyong-Seok, OS Kim, Seop, OV Kim, Sungho, OC Kim, Wan-Soo, OU Kim, Young Ki, 00 Kimura, Taiki, 0H Klinkhamer, Friso, OT Komaki, Takamitsu, OY Küchler, Bernd, Ol Kurosu, Akihiko, 17 Kwon, Yonghwi, 0C La Greca, R., 1C LaCour, Pat, 09 Lamb, James, 0J Lambregts, Cees, 0S Lan, Andy, 11 Lang, Jun, OB Lee, Chih-Jie, 11 Lee, Seonho, OV Li, Chen, 0A Li, Ming, 0B Limmer, Tim, 0J Lin, Cheng-Shuan, 11 Lin, Qi, 0X Liu, Jing Jing, 11 Liu, Liang, OB Liu, Peng, 07

Liu, Shiyuan, 19 Liu, Yi, 1A Liu, Zhunhua, OB Lomtscher, Patrick, 0U Lowes, Joyce, 0J Lu, Yifei, OB Ma, Jigang, 0S Ma, Won-Kwang, OS Ma, Xu, 16 Matsumoto, Takahiro, OY Matsunawa, Tetsuaki, OH Meyer, Mike, 0F Mimotogi, Shoji, OH Minoda, Ken, 0Y Mishima, Kazuhiko, OY Miyaharu, Takafumi, OY Miyamoto, Hirotaka, 17 Mizoguchi, Hakaru, 17 Morgenfeld, Bradley, 00 Morita, Naoki, 0W Moriya, Masato, 17 Nagano, Kouhei, 0M Niewczas, Mariusz, 0K Oga, Toshihiro, 13 Ohta, Takeshi, 17 Okudaira, Yosuke, 05 Okutomi, Akira, 0W Omran, Ahmed, 06 Pan, Bingyang, OB Pang, Linyong (Leo), OF, OK Park, Chan-Ha, 0S Park, Sang-Jun, OS Pearman, Ryan, OF, OK Pena, J. N., 1C Peng, Xiang, OB Pollak, Thilo, OT Pomerantsev, Michael, OK Poonawala, Amyn, 06 Rathi, Ashutosh, 09 Saitou, Takashi, 17 Santillan, Julius Joseph, 1B Sato, Futoshi, 13 Schatz, Jirka, Ol Sha, Lu, OK Sheng, Xichen, OB Shi, Xuelong, 0A Shi, Yating, 19 Shin, Youngsoo, OC Shu, Jason, 06 Sohara, Naoya, ON Stock, Hans-Juergen, 16 Stötzel, Christian, 0D Su, Bo, OK Sugimoto, Ayako, 0W Sungauer, E., 1C Suzuki, Kanji, 0M Takahashi, Kazuhiro, OY Takahashi, Ryotaro, ON

Takamatsu, Hirosuke, ON

Takasaki, Koichi, 0M Taki, Tomokazu, OY Tanaka, Hiroshi, 17 Tanaka, Satoshi, 17 Thaler, Thomas, 0D Thüring, Bernd, OT Tian, Yu, OB Tsamados, Dimitrios, Ol Tsiachris, Sotirios, OS Tsushima, Hiroaki, 17 Uemori, Nobutaka, 1B Ungar, P. Jeffrey, OF, OK Unno, Yasuyuki, OY Vandam, Clark, 06 Wang, Jinze, OB Wang, Kechang, 0K Wang, Weijun, OB Wang, Zhiqiang, 16 Wei, Yavi, 16 Weisbuch, Francois, OD Wu, Ying-chen, OB Xiao, Yanjun, OB Xie, Qian, 0B Xu, Ting Ting, 11 Yamaoka, Hiroshi, 1B Yamazaki, Taku, 13 Yan, Guanyong, 0B Yang, Dongyue, 00 Yang, Jinho, 0C Yang, Richer, 11 Yang, Terrance, OB Yang, Zhiyong, 19 Yao, Jun, 09 Yao, Shuxin, OB Yao, Yueliang, OB Yashiki, Satoshi, 05 Ye, Shawn, OJ Yi, Chunyan, 0B Yu, Dan, 1A Yu, Henry, OF Yu, Miao, OS Yuan, Wei, 0B Zeuner, Thomas, OD Zhang, Lei, 09 Zhao, Qian, OB Zhao, Yiqiong, OB Zhao, Yuhang, OA, OB Zheng, Zhenguo, 09 Zhu, Zhimin, OJ

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